Abstract (Basic): JP 62094914

Capacitor mfr. comprises (a) laminating a valve-functioning metal foil on one or both sides of an insulating material, (b) forming an anodic oxide film on the metal laminate foil, (c) coating a TCNQ complex on the anodic oxide film by vacuum evaph, plating to form an organic semiconductor film, (d) coating a metal on the organic semiconductor film by sputtering to form a cathode film to obtain a basic element and (e) coiling the basic element and providing electrode lead parts on both ends of the coiled element.

The Insulating material is made of a plastic sheet. The TCNQ complex includes 2,2'-bipyridinium (TCNQ)2, 4-hydroxy-N-

benzylanilinium (TCNQ)2, etc. etc.

USE/ADVANTAGE- the capacitor has no spacer but has a TCNQ complex-contg. Organic semiconductor film. Temp. stability is improved. @(8pp Dwg.No.0/4)@ Darwent Class: E14; L03; V01; E13; R42;

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MANUFACTURE OF TOROIDAL ELECTROLYTIC CAPACITOR

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- international:

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